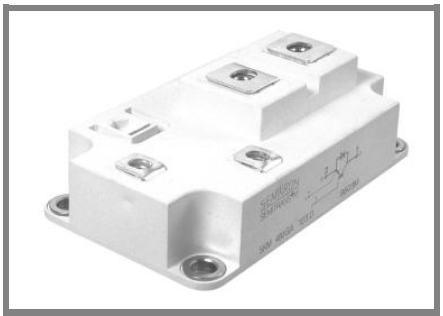
SKM 600GA176D



SEMITRANS® 4

Trench IGBT Modules

SKM 600GA176D

Features

- Homogeneous Si
- Trench = Trenchgate technology
- $V_{CE(sat)}$ with positive temperature coefficient
- High short circuit capability, self limiting to 6 x I_C

Typical Applications

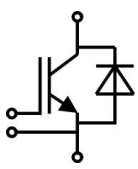
- AC inverter drives mains 575 - 790 V AC
- Public transport (auxiliary systems)

Remarks

- $I_{DC} \leq 500$ A limited for $T_{Terminal}$ = 100°C

Absolute Maximum Ratings	T_{case} = 25°C, unless otherwise specified			
Symbol	**Conditions**		**Values**	**Units**
IGBT				
V_{CES}	T_j = 25 °C		1700	V
I_C	T_j = 150 °C	T_c = 25 °C	660	A
		T_c = 80 °C	470	A
I_{CRM}	I_{CRM}=2xI_{Cnom}		800	A
V_{GES}			± 20	V
t_{psc}	V_{CC} = 1200 V; $V_{GE} \leq$ 20 V; V_{CES} < 1700 V	T_j = 125 °C	10	µs
Inverse Diode				
I_F	T_j = 150 °C	T_c = 25 °C	600	A
		T_c = 80 °C	410	A
I_{FRM}	I_{FRM}=2xI_{Fnom}		800	A
I_{FSM}	t_p = 10 ms; sin.	T_j = 150 °C	3800	A
Module				
$I_{t(RMS)}$			500	A
T_{vj}			- 40 ... +150	°C
T_{stg}			- 40 ... +125	°C
V_{isol}	AC, 1 min.		4000	V

Characteristics	T_{case} = 25°C, unless otherwise specified					
Symbol	**Conditions**		**min.**	**typ.**	**max.**	**Units**
IGBT						
$V_{GE(th)}$	V_{GE} = V_{CE}, I_C = 16 mA		5,2	5,8	6,4	V
I_{CES}	V_{GE} = 0 V, V_{CE} = V_{CES}	T_j = 25 °C		0,2	0,6	mA
V_{CE0}		T_j = 25 °C		1	1,2	V
		T_j = 125 °C		0,9	1,1	V
r_{CE}	V_{GE} = 15 V	T_j = 25°C		2,5	3,1	mΩ
		T_j = 125°C		3,9	4,5	mΩ
$V_{CE(sat)}$	I_{Cnom} = 400 A, V_{GE} = 15 V	T_j = 25°C$_{chiplev.}$		2	2,45	V
		T_j = 125°C$_{chiplev.}$		2,45	2,9	V
C_{ies}	V_{CE} = 25, V_{GE} = 0 V	f = 1 MHz		28,4		nF
C_{oes}				1,46		nF
C_{res}				1,17		nF
$t_{d(on)}$	R_{Gon} = 3 Ω	V_{CC} = 1200V		290		ns
t_r		I_C= 400A		70		ns
E_{on}		T_j = 125 °C		255		mJ
$t_{d(off)}$	R_{Goff} = 3 Ω	V_{GE} = ±15V		890		ns
t_f				160		ns
E_{off}				155		mJ
$R_{th(j-c)}$	per IGBT				0,044	K/W



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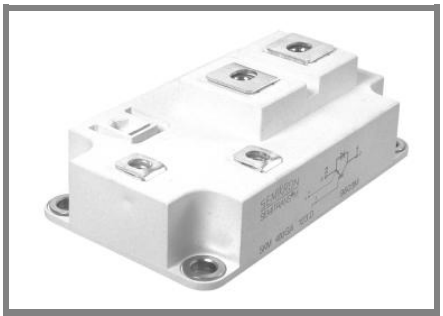
SKM 600GA176D



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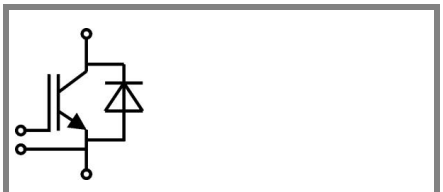

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Characteristics						
Symbol	**Conditions**		**min.**	**typ.**	**max.**	**Units**
Inverse Diode						
$V_F = V_{EC}$	I_{Fnom} = 400 A; V_{GE} = 0 V	T_j = 25 °C$_{chiplev.}$		1,6	1,9	V
		T_j = 125 °C$_{chiplev.}$		1,6	1,9	V
V_{F0}		T_j = 25 °C		1,1	1,3	V
r_F		T_j = 25 °C		1,3	1,5	mΩ
I_{RRM}	I_F = 400 A	T_j = 125 °C		510		A
Q_{rr}	di/dt = 5700 A/µs			155		µC
E_{rr}	V_{GE} = -15V V; V_{CC} = 1200 V			102		mJ
$R_{th(j-c)D}$	per diode				0,09	K/W
Module						
L_{CE}				15	20	nH
$R_{CC'+EE'}$	res., terminal-chip	T_{case}= 25 °C		0,18		mΩ
		T_{case}= 125 °C		0,22		mΩ
$R_{th(c-s)}$	per module				0,038	K/W
M_s	to heat sink M6		3		5	Nm
M_t	to terminals M6 (M4)		2,5 (1,1)		5 (2)	Nm
w					330	g

This is an electrostatic discharge sensitive device (ESDS), international standard IEC 60747-1, Chapter IX.

This technical information specifies semiconductor devices but promises no characteristics. No warranty or guarantee expressed or implied is made regarding delivery, performance or suitability.

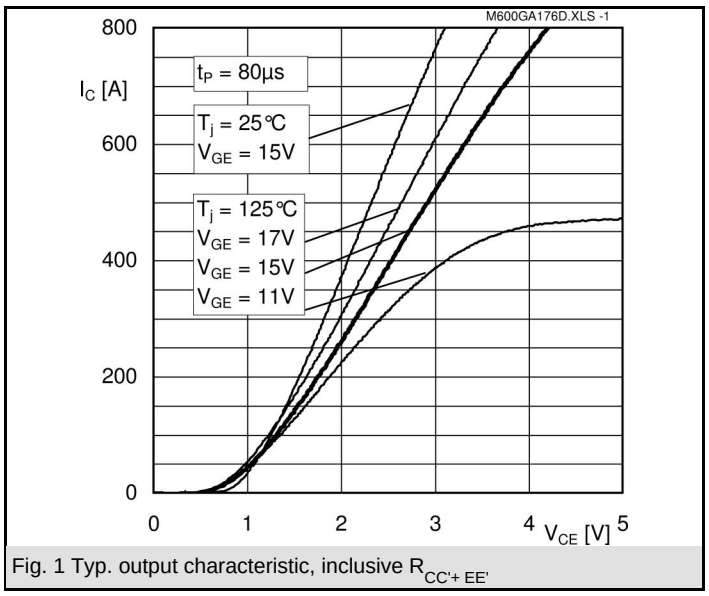

Fig. 1 Typ. output characteristic, inclusive $R_{CC'+EE'}$

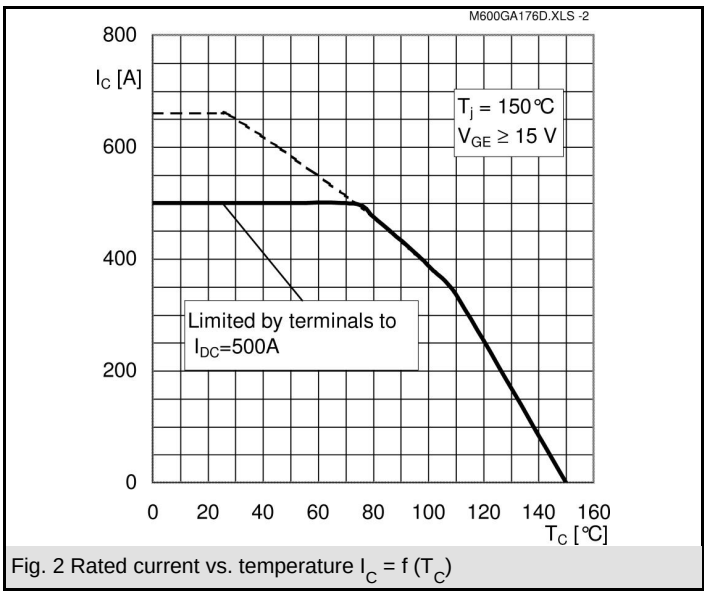

Fig. 2 Rated current vs. temperature $I_C = f(T_C)$

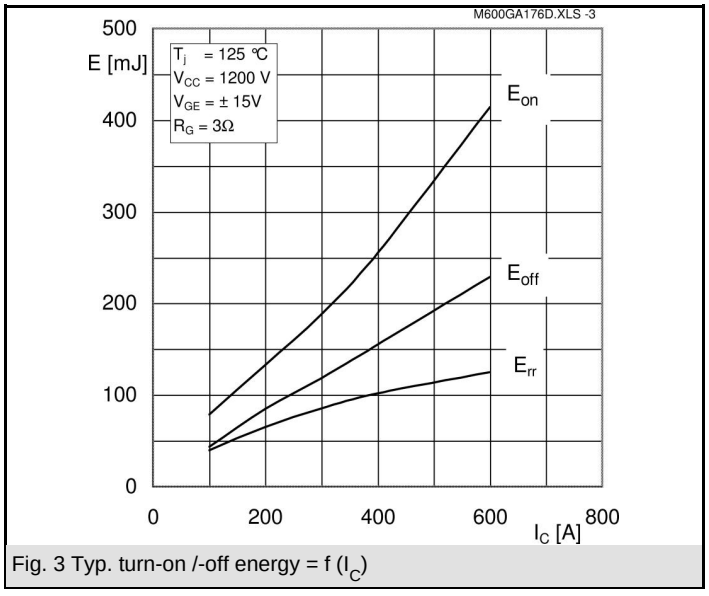

Fig. 3 Typ. turn-on /-off energy = f (I_C)

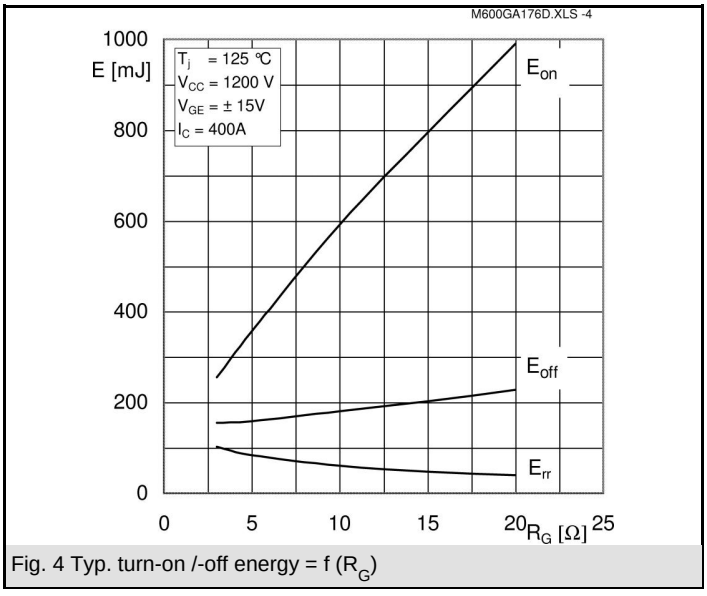

Fig. 4 Typ. turn-on /-off energy = f (R_G)

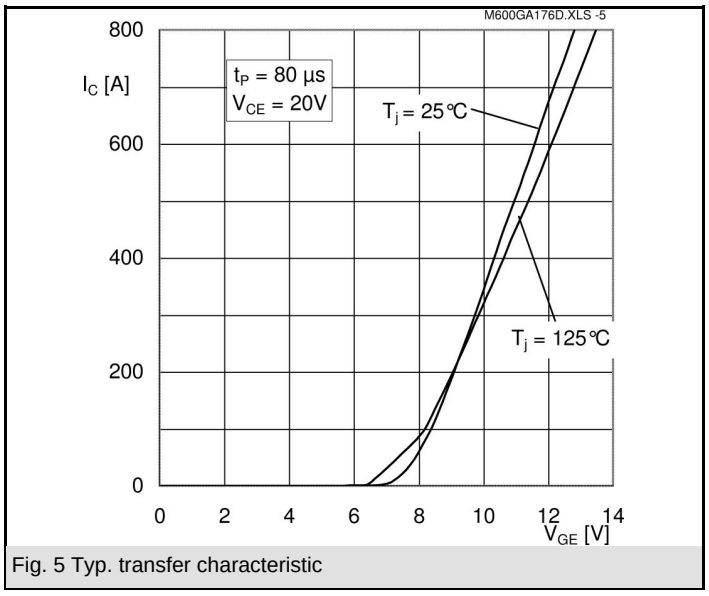

Fig. 5 Typ. transfer characteristic

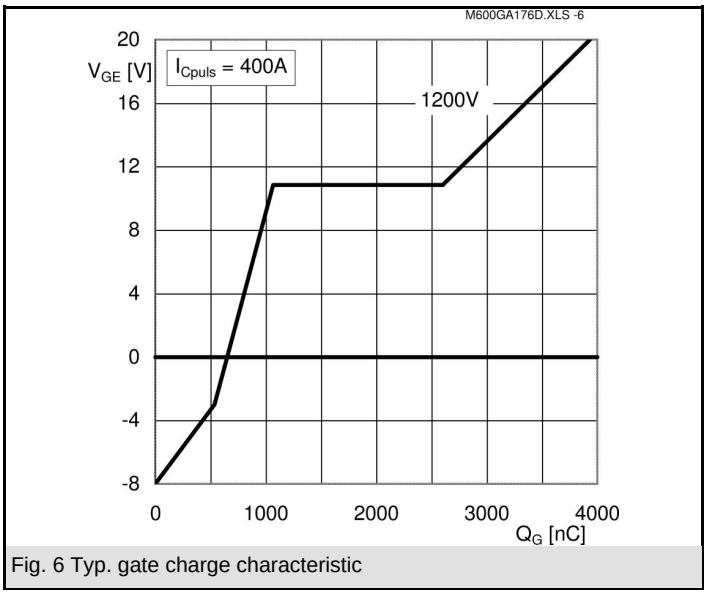

Fig. 6 Typ. gate charge characteristic

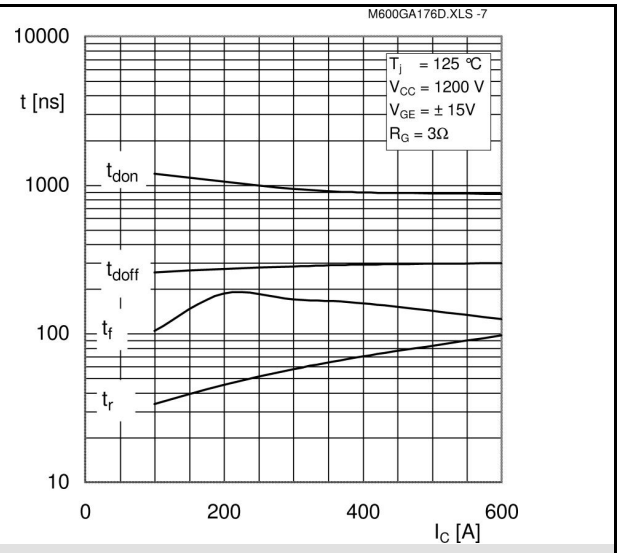

Fig. 7 Typ. switching times vs. I_C

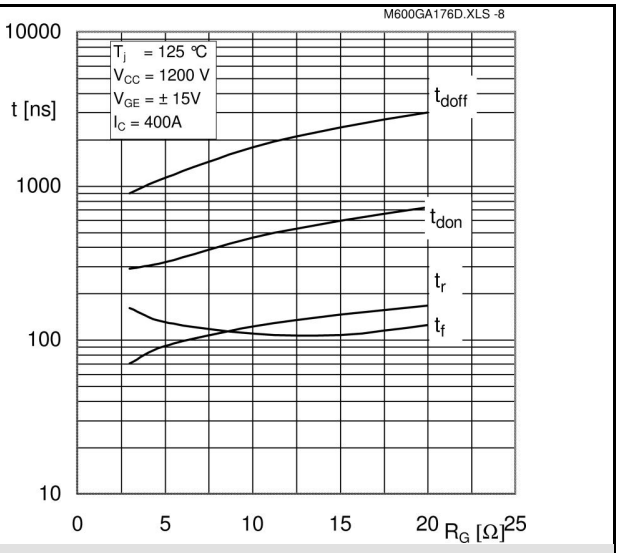

Fig. 8 Typ. switching times vs. gate resistor R_G

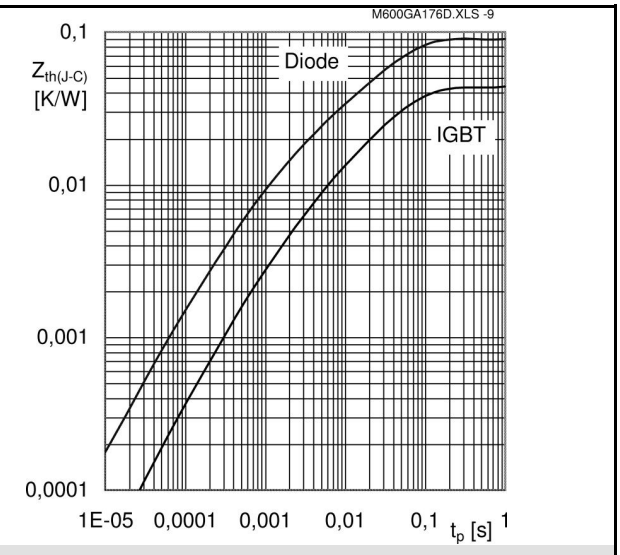

Fig. 9 Transient thermal impedance

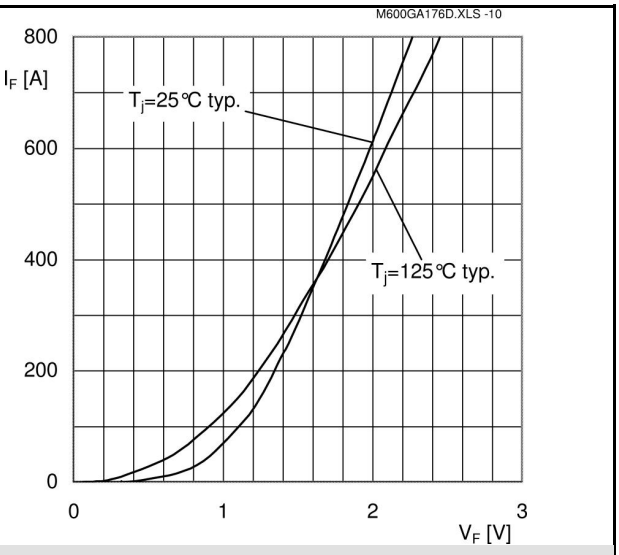

Fig. 10 CAL diode forward characteristic

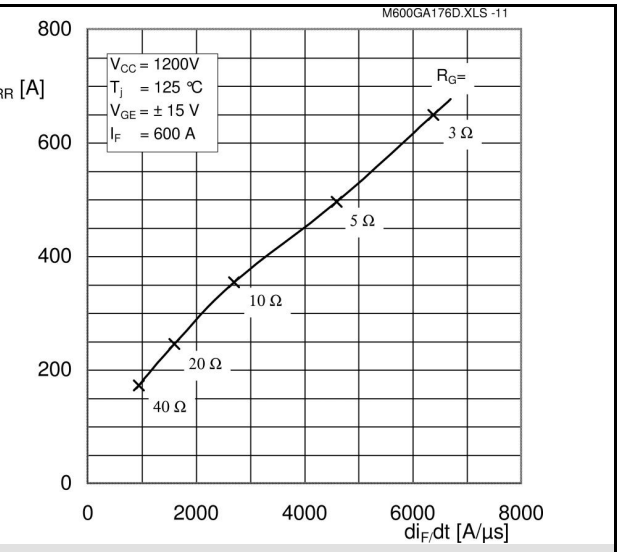

Fig. 11 Typ. CAL diode peak reverse recovery current

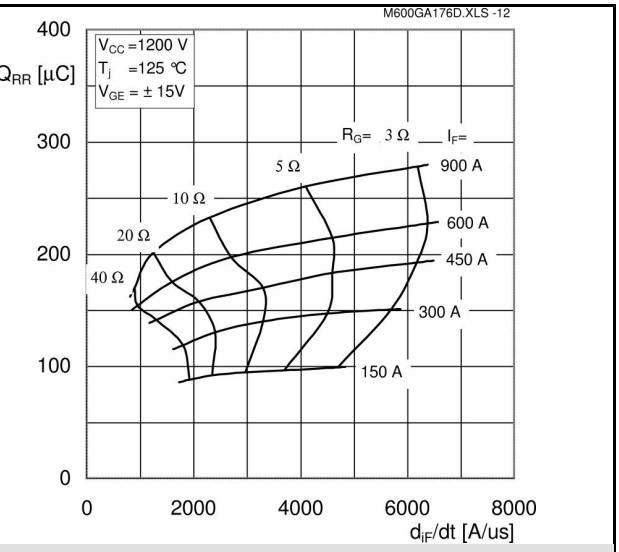

Fig. 12 Typ. CAL diode recovered charge

SKM 600GA176D

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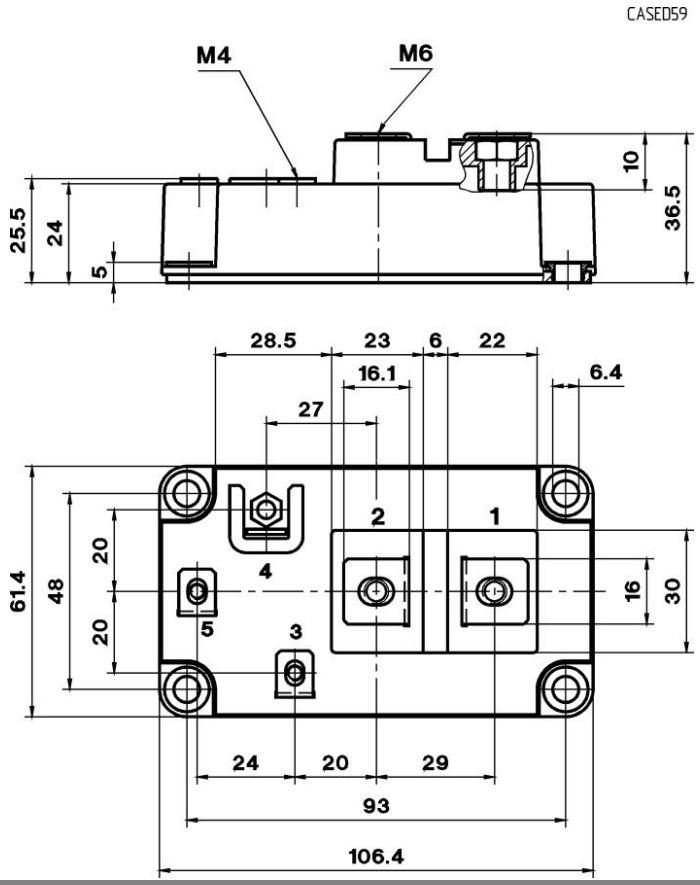
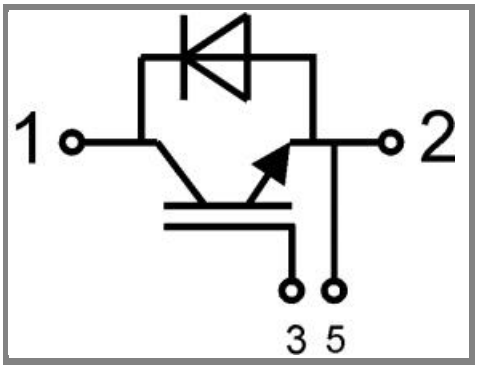


Case D 59



GA Case D59

